2SB1252

Silicon PNP epitaxial planar type Darlington

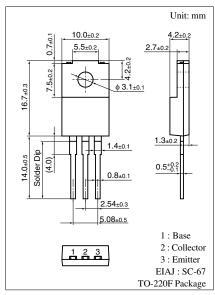
For power amplification Complementary to 2SD1892

■ Features

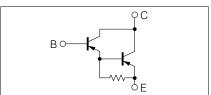
- Optimum for 35 W Hi-Fi output
- High forward current transfer ratio h_{FE}: 5 000 to 30 000
- \bullet Low collector to emitter saturation voltage $V_{\text{CE(sat)}}\!\!:<\!2.5~\text{V}$
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base voltage		V_{CBO}	-120	V
Collector to emitter voltage		V_{CEO}	-100	V
Emitter to base voltage		V_{EBO}	-5	V
Peak collector current		I_{CP}	-8	A
Collector current		I_C	-5	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	45	W
dissipation	$T_a = 25^{\circ}C$		2	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C



Internal Connection



■ Electrical Characteristics $T_C = 25$ °C

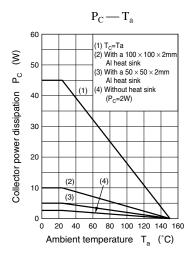
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -120 \text{ V}, I_E = 0$			-100	μΑ
	I_{CEO}	$V_{CE} = -100 \text{ V}, I_{B} = 0$			-100	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$			-100	μΑ
Collector to emitter voltage	V_{CEO}	$I_C = -30 \text{ mA}, I_B = 0$	-100			V
Forward current transfer ratio	h _{FE1}	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ A}$	2 000			
	h _{FE2} *	$V_{CE} = -5 \text{ V}, I_C = -4 \text{ A}$	5 000		30 000	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = -4 \text{ A}, I_{\rm B} = -4 \text{ mA}$			-2.5	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = -4 \text{ A}, I_{\rm B} = -4 \text{ mA}$			-3.0	V
Transition frequency	f_T	$V_{CE} = -10 \text{ V}, I_{C} = -0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_C = -4 \text{ A}, I_{B1} = -4 \text{ mA}, I_{B2} = 4 \text{ mA},$		1.0		μs
Storage time	t _{stg}	$V_{CC} = -50 \text{ V}$		0.8		μs
Fall time	$t_{\rm f}$			1.0		μs

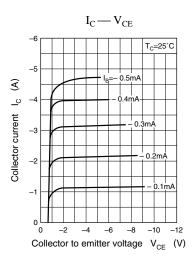
Note) *: Rank classification

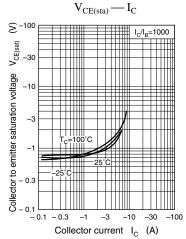
Rank	Q	Р		
h _{FE2}	5 000 to 15 000	8 000 to 30 000		

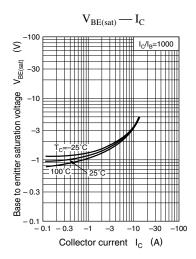
Panasonic 1

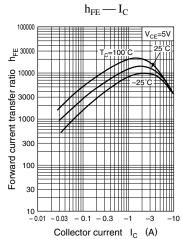
2SB1252 Power Transistors

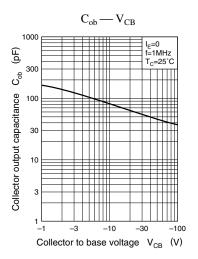


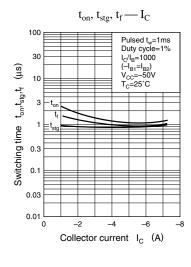


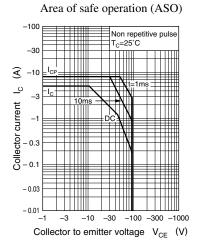




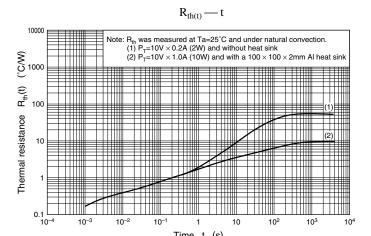








Power Transistors 2SB1252



Time t (s)

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